#### **LECTURE 3:** Refrigeration







## **Refrigeration "on-chip"**

Thermoelectric refrigeration

Peltier refrigerators, Peltier 1834

Thermionic refrigeration, Mahan, 1994 Korotkov and Likharev, 1999

Quantum-dot refrigerator, Edwards et. al., 1993 Experiment: Prance et al., PRL 102, 146602 (2009).



FIG. 1. (a) Schematic and (b) energy-level diagram of a theoretical design for a quantum-dot refrigerator which could be made using a DDEG in GAAs/AL\_Ga.\_\_AS. The reservoir R is cooled to  $T_0$  as its Fermi-Dirac distribution is sharpened by resonant tunneling through quantum dots  $D_1$  and  $D_2$  to the electrodes  $V_L$  and  $V_R$ . A heat load L can be coupled electronically to R via tunneling.

# Dissipation in transport through a barrier - tunneling



Dissipation generated by a tunneling event in a junction biased at voltage V

$$\Delta \boldsymbol{Q} = (\mu_1 \boldsymbol{-} \boldsymbol{E}) \boldsymbol{+} (\boldsymbol{E} \boldsymbol{-} \mu_2) = \mu_1 \boldsymbol{-} \mu_2 = \boldsymbol{e} \boldsymbol{V}$$

 $\Delta Q = T \Delta S$  is first distributed to the electron system, then typically to the lattice by electron-phonon scattering

For average current *I* through the junction, the total average power dissipated is naturally

 $P = (I e) \Delta Q = IV$ 

## **Energy current in a tunnel junction**

Energy current (from conductor 1)



$$P(V) = \frac{1}{e^2 R_T} \int (E - eV) n_1 (E - eV) n_2(E) [f_1(E - eV) - f_2(E)] dE$$
  
Compare to:  $I(V) = \frac{1}{e^2 R_T} \int eN_1 (E - eV) N_2(E) [f_1(E - eV) - f_2(E)] dE$ 

#### For a NIN junction (constant DOSes)

$$P(V) = \frac{1}{e^2 R_T} \int (E - eV) [f(E - eV) - f(E)] dE = -\frac{V^2}{2R_T}$$
  
= - IV/2

The Joule power is distributed equally between 1 and 2 in this case.

### **Electronic NIS-coolers**



$$P_{\rm NIS} = \frac{1}{e^2 R_T} \int dE (E - eV) n_S(E) [f_N(E - eV) - f_S(E)]$$

Optimum cooling power is reached at  $V \cong \Delta/e$ :

$$P_{\rm NIS} \approx 0.6 \frac{\Delta^2}{e^2 R_T} (\frac{k_B T_N}{\Delta})^{3/2}$$

Efficiency (coefficient of performance) of a NIS junction cooler:

$$\eta \simeq k_B T / \Delta$$

For reviews, see Giazotto et al., Rev. Mod. Phys. 78, 217 (2006); Muhonen et al., Reports on Progress in Physics 75, 046501 (2012).

### **SINIS** structure



Symmetric back-to-back structure provides equal cooling by the two junctions.

### **Early experiments**



M. Leivo et al., 1996

# Large cooling power NIS refrigerators



AI

Large-area (70 X 4  $\mu$ m<sup>2</sup>) photolithographic junctions, cooling power 1 nW at 300 mK Nguyen et al. 2013





### More recent NIS coolers

#### **Platform refrigerators**





P. Lowell et al., NIST, 2013

H. Nguyen et al., Helsinki, 2015



Two-stage refrigerator, H. Nguyen et al., 2016

# Cooling of a superconductor (SIS'IS cooler)



 $\dot{Q} = \frac{1}{e^2 R_T} \int_{-\infty}^{\infty} [f(\boldsymbol{\epsilon}, T_{e2}) - f(\boldsymbol{\epsilon} - eV, T_{e1})]$ 

 $\times N_2(\epsilon)N_1(\epsilon - eV)\epsilon d\epsilon$ 





Ti – Al sample  $[T_{\rm C}({\rm Ti}) = 0.5 \text{ K}, T_{\rm C}({\rm Al}) = 1.3 \text{ K}]$ 

#### COOLING FROM NORMAL TO SUPERCONDUCTING STATE

A. J. Manninen et al., Appl. Phys. Lett. 74, 3020 (1999).

### Low temperature limit

SNS proximity Josephson junction is a low-dissipative, unsaturating thermometer at low *T*: lowest T = 20 mK (+/- 10 mK). J. Peltonen et al, unpublished.



# Influence of Andreev current on electron cooling

Two-electron tunneling becomes important in transparent junctions. Maisi et al. 2011, 2013

Effective at low bias voltages, dissipation  $I_{AR}V$  in N electrode.





εV

(a)

Rajauria et al., 2008

# Energy relaxation by magnetic field in coolers

Magnetic field enhanced cooling



# Sc aluminium dot in magnetic field

![](_page_13_Figure_1.jpeg)

### **Higher temperatures**

![](_page_14_Figure_1.jpeg)

O. Quaranta et al., APL 98, 032501 (2011): Cooling Al from 1 K to 0.4 K.

# **Cooling nanomechanical beams**

![](_page_15_Figure_1.jpeg)

Cooling phonons as well Koppinen et al PRL 2009 Is e-ph coupling as in bulk? *T*<sup>3</sup> instead of *T*<sup>5</sup>? Hekking et al, PRB 2008, Muhonen et al, APL 2009

## Schottky barrier cooler

Same working principle as in SINIS, but no oxide barrier needed: S-Sm interface forms a Schottky barrier.  $s \sqcap s_m \sqcap s$ 

10

Thermometer

n++ SOI film

BOX, SiO,

A. Savin et al, APL **79**, 1471 (2001)

AI

(b)

S-Sm cooler

junction

![](_page_16_Figure_3.jpeg)

### Quantum dot cooler

![](_page_17_Figure_1.jpeg)

# Tunable NIS refrigerator – "heat transistor"

O. Saira et al., PRL 99, 027203 (2007)

![](_page_18_Figure_2.jpeg)

# **RF NIS-refrigerator**

No net charge current, but finite cooling power

JP et al., PRL 98, 037201 (2007); S. Kafanov et al., PRL 103, 120801 (2009)

250nm

 $V_{g,rf}$ 

4

2

20

(b)

0

0.5

 $Q_g/e$ 

(a)\_\_\_\_\_

![](_page_19_Figure_3.jpeg)

### **SET-cooler**

![](_page_20_Figure_1.jpeg)

# **Experimental status of electronic** refrigeration

Nahum et al. 1994 *Demonstration of NIS cooling* Leivo et al. 1996 Cooling electrons 300 mK -> 100 mK by SINIS Manninen et al. 1999 Cooling by SIS'IS Manninen et al. 1997, Luukanen et al. 2000 *Lattice refrigeration by SINIS* Savin et al. 2001 S – Schottky – Semiconductor – Schottky – S cooling Clark et al. 2005, Miller et al. 2008 x-ray detector refrigerated by SINIS Prance et al. 2009 Electronic refrigeration of a 2DEG Kafanov et al. 2009 *RF-refrigeration* Quaranta et al 2011 Cooling from 1 K to 0.4 K Lowell et al. 2013 Macroscopic NIS refrigerator Nguyen et al 2013 Cooling power up to 1 nW Nguyen et al. 2016 Cascade refrigerator

For reviews, see Rev. Mod. Phys. 78, 217 (2006); Reports on Progress in Physics 75, 046501 (2012).

#### **Refrigeration of a "bulk" object**

![](_page_21_Picture_4.jpeg)

A. Clark et al., Appl. Phys. Lett. 86, 173508 (2005).